Express Mail Number EV 342470 45945 PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re l	Patent Application of) Group Art Unit: Unknown
Vladis	lav Vashchenko et al.)) Examiner: Unknown
Application No. New)) INFORMATION DISCLOSURE) STATEMENT
Filed:	Herewith) SINIEFIENI
For:	SILICON CONTROLLED RECTIFIER STRUCTURE WITH IMPROVED PUNCH THROUGH RESISTANCE	())))

Mail Stop Patent Application Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Applicants submit herewith information of which applicants are aware, which applicants believe may be material to the examination of this application and in respect of which there may be a duty to disclose in accordance with 37 CFR § 1.56.

This Information Disclosure Statement:

- (a) [X] accompanies the new patent application submitted herewith. 37 CFR § 1.97(a).
- (b) [] is filed within three months after the filing date of the application or within three months after the date of entry of the national stage of a PCT application as set forth in 37 CFR § 1.491.
- (c) [] as far as is known to the undersigned, is filed before the mailing date of a first Office Action on the merits.

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(d) [] is filed after the first office action and more than three months after the application's filing date or PCT national stage date of entry filing but, as far as is known to the undersigned, prior to the mailing date of either a final rejection or a notice of allowance, whichever occurs first, and is accompanied by either the fee (\$180) set forth in 37 CFR § 1.17(p) or a certification as specified in 37 CFR § 1.97(e), as checked below.

(e) [] is filed after the mailing date of either a final rejection or a notice of allowance, whichever occurred first, and is accompanied by the fee (\$180) set forth in 37 CFR § 1.17(i)(1) and a certification as specified in 37 CFR § 1.97(e), as checked below. This document is to be considered as a petition requesting consideration of the information disclosure statement.

[If either of boxes (d) or (e) are checked above, the following "certification" under 37 CFR § 1.97(e) may need to be completed.] The undersigned certifies that:

- (f) [] Each item of information contained in the information disclosure statement was cited in a communication mailed from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this information disclosure statement.
- (g) [] No item of information contained in this information disclosure statement was cited in a communication mailed from a foreign patent office in a counterpart foreign application or, to the knowledge of the undersigned after making reasonable inquiry, was known to any individual designated in 37 CFR § 1.56(c) more than three months prior to the filing of this information disclosure statement.

(i) [] none (i) [] only those listed below:

A list of the patent(s) or publications(s) is set forth on the attached Form PTO-1449 (Modified). A copy of the items on PTO-1449 (Modified) is supplied herewith:

	('')	[M] Cacil	(1) [] /10/10	O) [] oiny those	instea below.	
	Those	e patent(s) or p	ublication(s) wh	ich are marked w	vith an asterisk (*) in	the
attache	ed form	m PTO-1449 (Mo	odified) are not	supplied because	they were previous	ly cited by
or subr	nitted	to the Office in	a prior applicat	ion no		_ and relied
upon ir	this	application for a	n earlier filing c	late under 35 U.S	S.C. § 120.	

A concise explanation of relevance of the described above and attached information is:

(k)	[X]	not given
(I)	[]	given for each listed item

(h) [X] each

- (m) [] given for only non-English language listed item(s) [Required]
- (n) [] is in the form of an English language copy of a Search Report from a foreign patent office, issued in a counterpart application, which refers to the relevant portions of the references [copy attached].

While the information disclosed in this Information Disclosure Statement may be "material" pursuant to 37 CFR § 1.56, it is not intended to constitute an admission that the

information referred to is "prior art" for this invention unless specifically designated as such.

In accordance with 37 CFR § 1.97(g), the filing of this Information Disclosure Statement shall not be construed to mean that a search has been made or that no other material information as defined in 37 CFR § 1.56(a) exists. It is submitted that the Information Disclosure Statement is in compliance with 37 CFR § 1.98 and MPEP § 609 and the Examiner is respectfully requested to consider the above-described and attached information.

Respectfully submitted,

Dated: X - 27 - 0.3

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Attorney for Assignee

Atty. Docket No: 100-22600 (P05659)

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Express Mail Number EV342470459US FORM PTO-1449 Dock t Number (Optional) Applicati n No. 100-22600 (P05659) Nw INFORMATION DISCLOSURE CITATION Applicant(s) IN AN APPLICATION Vladislav Vashchenko et al. **Group Art Unit** Filing Dat (Use several sheets if necessary) H r with Unkn wn **U.S. PATENT DOCUMENTS EXAMINER DOCUMENT NUMBER** DATE NAME CLASS **SUBCLASS FILING DATE** INITIAL IF APPROPRIATE FOREIGN PATENT DOCUMENTS DOCUMENT NUMBER COUNTRY DATE **CLASS** SUBCLASS Translation Yes

	OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)
	Julian Z. Chen, Ajith Amerasekera and Tom Vrotsos, "Bipolar SCR ESD Protection Circuit for High Speed Submicron Bipolar/BiCMOS Circuits", IEDM, pps. 337-340, (14.1.1 - 14.1.4), 1995, IEEE.
EXAMINER	DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP \$609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.